International TOR Rectifier

Features

- Advanced Planar Technology
- Low On-Resistance
- Logic Level
- N Channel MOSFET
- Surface Mount
- Available in Tape & Reel
- 150°C Operating Temperature
- Automotive [Q101] Qualified
- Lead-Free, RoHS Compliant

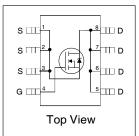
Description

Specifically designed for Automotive applications, these HEXFET® Power MOSFET's in a Dual SO-8 package utilize the lastest processing techniques to achieve extremely low on-resistance per silicon area. Additional features of these Automotive qualified HEXFET Power MOSFET's are a 150°C junction operating temperature, fast switching speed and improved repetitive avalanche rating. These benefits combine to make this design an extremely efficient and reliable device for use in Automotive applications and a wide variety of other applications.

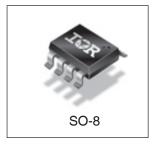
The efficient SO-8 package provides enhanced thermal characteristics and dual MOSFET die capability making it ideal in a variety of power applications. This dual, surface mount SO-8 can dramatically reduce board space and is also available in Tape & Reel.

AUIRF7805Q

HEXFET® Power MOSFET



V _{(BR)DSS}	3	30V
R _{DS(on)}	typ.	9.2m Ω
	max.	11m Ω
I _D		13A



G	D	S
Gate	Drain	Source

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is $25^{\circ}C$, unless otherwise specified.

	Parameter	Max.	Units	
V_{DS}	Drain-to-Source Voltage	30	V	
V _{GS}	Gate-to-Source Voltage	± 12		
I _D @ T _A = 25°C	Continuous Drain Current, V _{GS} @ 10V	13		
I _D @ T _A = 70°C	Continuous Drain Current, V _{GS} @ 10V	10	Α	
I _{DM}	Pulsed Drain Current ①	100		
P _D @T _A = 25°C	Power Dissipation 3	2.5	W	
P _D @T _A = 70°C	Power Dissipation ③	1.6		
	Linear Derating Factor	0.02	W/°C	
T _J	Operating Junction and	-55 to + 150	°C	
T _{STG}	Storage Temperature Range			

Thermal Resistance

	Parameter	Тур.	Max.	Units
$R_{\theta JL}$	Junction-to-Drain Lead [®]		20	°C/W
$R_{\theta JA}$	Junction-to-Ambient ®		50	

HEXFET® is a registered trademark of International Rectifier.

^{*}Qualification standards can be found at http://www.irf.com/

Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
BV _{DSS}	Drain-to-Source Breakdown Voltage®	30			V	$V_{GS} = 0V, I_D = 250\mu A$
R _{DS(on)}	Static Drain-to-Source On-Resistance®		9.2	11	mΩ	V _{GS} = 4.5V, I _D = 7.0A ②
V _{GS(th)}	Gate Threshold Voltage ®	1.0		3.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
I _{DSS}	Drain-to-Source Leakage Current			70		$V_{DS} = 30V$, $V_{GS} = 0V$
				10	μΑ	$V_{DS} = 24V, V_{GS} = 0V$
				150		$V_{DS} = 24V, V_{GS} = 0V, T_{J} = 100^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage			100	nA	V _{GS} = 12V
	Gate-to-Source Reverse Leakage			-100] ''A	V _{GS} = -12V

Dynamic Electrical Characteristics @ $T_J = 25$ °C (unless otherwise specified)

Q_g	Total Gate Charge		22	31		$V_{GS} = 5.0V$
Q _{gs1}	Pre-Vth Gate-to-Source Charge		3.7			V _{DS} = 16V
Q _{gs2}	Post-Vth Gate-to-Source Charge		1.4		nC	I _D = 7.0A
Q_{gd}	Gate-to-Drain Charge		6.8			
Q _{sw}	Switch Charge (Q _{gs2} + Q _{gd})		8.2	11.5		
Q _{oss}	Output Charge		3.0	3.6	nC	$V_{DS} = 16V$, $V_{GS} = 0V$
R_G	Gate Resistance	0.5		1.7	Ω	
$t_{d(on)}$	Turn-On Delay Time		16			$V_{DD} = 16V, V_{GS} = 4.5V$ ②
t _r	Rise Time		20			I _D = 7.0A
t _{d(off)}	Turn-Off Delay Time		38		ns	$R_G = 2\Omega$
t _f	Fall Time		16			Resistive Load

Diode Characteristics

	Parameter	Min.	Тур.	Max.	Units	Conditions
Is	Continuous Source Current			2.5		MOSFET symbol
	(Body Diode) ①			2.5	Α	showing the
I _{SM}	Pulsed Source Current			106	_ ^	integral reverse
	(Body Diode)			100		p-n junction diode.
V_{SD}	Diode Forward Voltage ®			1.2	V	$T_J = 25^{\circ}C$, $I_S = 7.0A$, $V_{GS} = 0V$
Q _{rr}	Reverse Recovery Charge ⁽⁴⁾		88			di/dt = 700A/µs
			00		ns	$V_{DS} = 16V, V_{GS} = 0V, I_{S} = 7.0A$
Q _{rr(s)}	Reverse Recovery Charge (with Parallel Schottky) (4) 55		n n C	di/dt = 700A/µs (with 10BQ040)		
				$V_{DS} = 16V, V_{GS} = 0V, I_{S} = 7.0A$		

Notes:

- $\begin{array}{ll} \textcircled{1} & \text{Repetitive rating; pulse width limited by max. junction temperature.} \\ \textcircled{2} & \text{Pulse width} \leq 300 \ \mu\text{s; duty cycle} \leq 2\%. \\ \textcircled{3} & \text{When mounted on 1 inch square copper board, t < 10 sec.} \\ \textcircled{4} & \text{Typ = measured Q}_{\text{oss}} \\ \textcircled{5} & \text{R}_{_{\theta}} \text{ is measured at T}_{_{J}} \text{ of approximately } 90^{\circ}\text{C.} \\ \textcircled{6} & \text{Devices are } 100\% \text{ tested to these parameters.} \\ \end{array}$

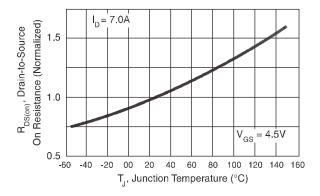
Qualification Information[†]

		Automotive (per AEC-Q101) ††			
		Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.			
Moisture Sensiti	Moisture Sensitivity Level SO-8 MSL1				
	Machine Model	Class M3(+/- 300V) ^{†††} (per AEC-Q101-002)			
ESD	Human Body Model	Class H1B(+/- 1000V) ^{†††} (per AEC-Q101-001)			
Charged Device Model		Class C5(+/- 2000V) ^{†††} (per AEC-Q101-005)			
RoHS Complian	t	Yes			

[†] Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

^{††} Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.

^{†††} Highest passing voltage



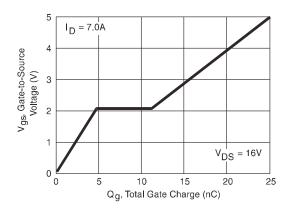
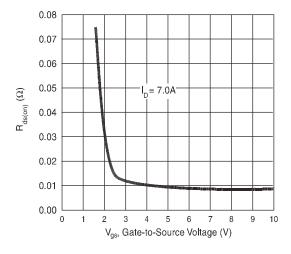


Fig 1. Normalized On-Resistance vs. Temperature

Fig 2. Typical Gate Charge vs. Gate-to-Source Voltage



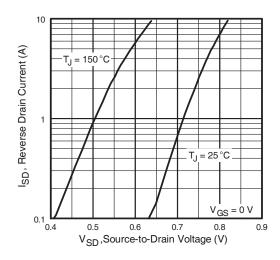


Fig 3. Typical Rds(on) vs. Gate-to-Source Voltage

Fig 4. Typical Source-Drain Diode Forward Voltage

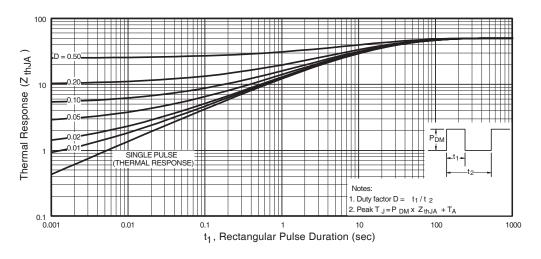
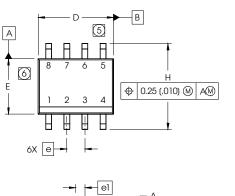


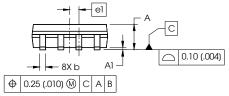
Figure 5. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

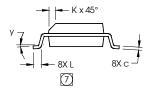
SO-8 Package Outline

Dimensions are shown in millimeters (inches)



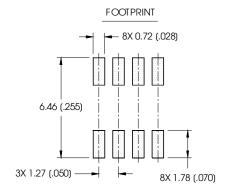
DIM	INCHES		MILLIM	ETERS	
DIIVI	MIN	MAX	MIN	MAX	
Α	.0532	.0688	1.35	1.75	
Al	.0040	.0098	0.10	0.25	
b	.013	.020	0.33	0.51	
С	.0075	.0098	0.19	0.25	
D	.189	.1968	4.80	5.00	
Е	.1497	.1574	3.80	4.00	
е	.050 BASIC		1.27 BASIC		
еl	.025 BASIC		0.635 BASIC		
Н	.2284	.2440	5.80	6.20	
K	.0099	.0196	0.25	0.50	
L	.016	.050	0.40	1.27	
У	0°	8°	0°	8°	



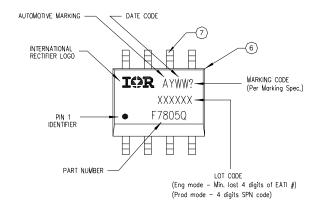


NOTES:

- 1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
- 2. CONTROLLING DIMENSION: MILLIMETER
- 3. DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
- 4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.
- (5) DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 (.006).
- (6) DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 (.010).
- (7) DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO ASUBSTRATE.



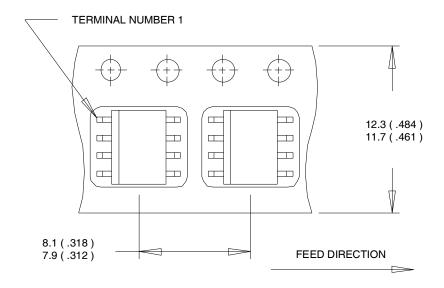
SO-8 Part Marking



TOP MARKING (LASER)

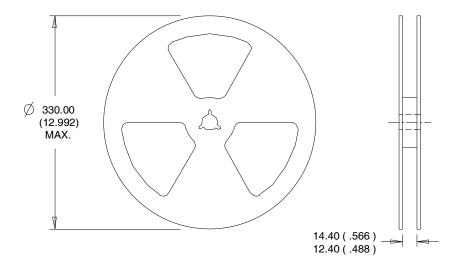
SO-8 Tape and Reel

Dimensions are shown in millimeters (inches)



NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS(INCHES).
- 3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



NOTES:

- ${\bf 1.\ CONTROLLING\ DIMENSION: MILLIMETER.}\\$
- 2. OUTLINE CONFORMS TO EIA-481 & EIA-541.

Ordering Information

Base part	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRF7805Q	SO-8	Tube	95	AUIRF7805Q
		Tape and Reel	4000	AUIRF7805QTR

AUIRF7805Q

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For technical support, please contact IR's Technical Assistance Center http://www.irf.com/technical-info/

WORLD HEADQUARTERS:

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